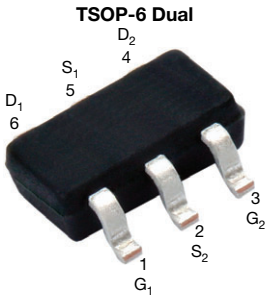
# Dual N-Channel 30 V (D-S) MOSFET



Top View

**Marking code:** MH

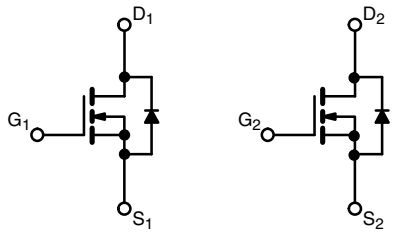
## FEATURES

- TrenchFET® power MOSFET
- 100% $R_g$ tested
- Material categorization:
  for definitions of compliance please see
  www.vishay.com/doc?99912

Pb-free
RoHS COMPLIANT
HALOGEN FREE

## APPLICATIONS

- Load switch for portable applications
- DC/DC converters



N-Channel MOSFET N-Channel MOSFET

| PRODUCT SUMMARY | |
|---|---|
| $V_{DS}$ (V) | 30 |
| $R_{DS(on)}$ max. (Ω) at $V_{GS}$ = 10 V | 0.058 |
| $R_{DS(on)}$ max. (Ω) at $V_{GS}$ = 4.5 V | 0.073 |
| $Q_g$ typ. (nC) | 1.8 |
| $I_D$ (A) [a] | 3.7 |
| Configuration | Dual |

| ORDERING INFORMATION | |
|---|---|
| Package | TSOP-6 |
| Lead (Pb)-free and halogen-free | Si3932DV-T1-GE3 |

**ABSOLUTE MAXIMUM RATINGS** ($T_A$ = 25 °C, unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNIT |
|---|---|---|---|---|
| Drain-source voltage | | $V_{DS}$ | 30 | V |
| Gate-source voltage | | $V_{GS}$ | ± 20 | |
| Continuous drain current ($T_J$ = 150 °C) | $T_C$ = 25 °C | $I_D$ | 3.7 | A |
| | $T_C$ = 70 °C | | 3 | |
| | $T_A$ = 25 °C | | 3.4 [b, c] | |
| | $T_A$ = 70 °C | | 2.7 [b, c] | |
| Pulsed drain current | | $I_{DM}$ | 15 | |
| Continuous source-drain diode current | $T_C$ = 25 °C | $I_S$ | 1.17 | |
| | $T_A$ = 25 °C | | 0.95 [b, c] | |
| Maximum power dissipation | $T_C$ = 25 °C | $P_D$ | 1.4 | W |
| | $T_C$ = 70 °C | | 0.9 | |
| | $T_A$ = 25 °C | | 1.14 [b, c] | |
| | $T_A$ = 70 °C | | 0.73 [b, c] | |
| Operating junction and storage temperature range | | $T_J$, $T_{stg}$ | -55 to +150 | °C |
| Soldering recommendations (peak temperature) [d, e] | | | 260 | |

**THERMAL RESISTANCE RATINGS**

| PARAMETER | | SYMBOL | TYPICAL | MAXIMUM | UNIT |
|---|---|---|---|---|---|
| Maximum junction-to-ambient [b, d] | t ≤ 5 s | $R_{thJA}$ | 93 | 110 | °C/W |
| Maximum junction-to-foot | Steady state | $R_{thJF}$ | 75 | 90 | |

**Notes**

a. $T_C$ = 25 °C
b. Surface mounted on 1" x 1" FR4 board
c. t = 5 s
d. Maximum under steady state conditions is 150 °C/W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| **SPECIFICATIONS** ($T_J$ = 25 °C, unless otherwise noted) | | | | | | |
|---|---|---|---|---|---|---|
| **PARAMETER** | **SYMBOL** | **TEST CONDITIONS** | **MIN.** | **TYP.** | **MAX.** | **UNIT** |
| **Static** | | | | | | |
| Drain-source breakdown voltage | $V_{DS}$ | $V_{GS}$ = 0 V, $I_D$ = 250 μA | 30 | - | - | V |
| $V_{DS}$ temperature coefficient | $\Delta V_{DS}/T_J$ | $I_D$ = 250 μA | - | 29 | - | mV/°C |
| $V_{GS(th)}$ temperature coefficient | $\Delta V_{GS(th)}/T_J$ | | - | -4 | - | |
| Gate-source threshold voltage | $V_{GS(th)}$ | $V_{DS}$ = $V_{GS}$, $I_D$ = 250 μA | 1.2 | - | 2.2 | V |
| Gate-source leakage | $I_{GSS}$ | $V_{DS}$ = 0 V, $V_{GS}$ = ± 20 V | - | - | ± 100 | nA |
| Zero gate voltage drain current | $I_{DSS}$ | $V_{DS}$ = 30 V, $V_{GS}$ = 0 V | - | - | 1 | μA |
| | | $V_{DS}$ = 30 V, $V_{GS}$ = 0 V, $T_J$ = 55 °C | - | - | 10 | |
| On-state drain current [a] | $I_{D(on)}$ | $V_{DS} \geq$ 5 V, $V_{GS}$ = 10 V | 10 | - | - | A |
| Drain-source on-state resistance [a] | $R_{DS(on)}$ | $V_{GS}$ = 10 V, $I_D$ = 3.4 A | - | 0.047 | 0.058 | Ω |
| | | $V_{GS}$ = 4.5 V, $I_D$ = 3 A | - | 0.058 | 0.073 | |
| Forward transconductance [a] | $g_{fs}$ | $V_{DS}$ = 15 V, $I_D$ = 3.4 A | - | 10 | - | S |
| **Dynamic [b]** | | | | | | |
| Input capacitance | $C_{iss}$ | $V_{DS}$ = 15 V, $V_{GS}$ = 0 V, f = 1 MHz | - | 235 | - | pF |
| Output capacitance | $C_{oss}$ | | - | 45 | - | |
| Reverse transfer capacitance | $C_{rss}$ | | - | 16 | - | |
| Total gate charge | $Q_g$ | $V_{DS}$ = 15 V, $V_{GS}$ = 10 V, $I_D$ = 3.4 A | - | 3.7 | 6 | nC |
| | | $V_{DS}$ = 15 V, $V_{GS}$ = 4.5 V, $I_D$ = 3.4 A | - | 1.8 | 3 | |
| Gate-source charge | $Q_{gs}$ | | - | 0.74 | - | |
| Gate-drain charge | $Q_{gd}$ | | - | 0.42 | - | |
| Gate resistance | $R_g$ | f = 1 MHz | 1 | 5 | 10 | Ω |
| Turn-on delay time | $t_{d(on)}$ | $V_{DD}$ = 15 V, $R_L$ = 5.6 Ω<br>$I_D \cong$ 2.7 A, $V_{GEN}$ = 4.5 V, $R_g$ = 1 Ω | - | 10 | 20 | ns |
| Rise time | $t_r$ | | - | 15 | 30 | |
| Turn-off delay time | $t_{d(off)}$ | | - | 10 | 20 | |
| Fall time | $t_f$ | | - | 10 | 20 | |
| Turn-on delay time | $t_{d(on)}$ | $V_{DD}$ = 15 V, $R_L$ = 5.6 Ω<br>$I_D \cong$ 2.7 A, $V_{GEN}$ = 10 V, $R_g$ = 1 Ω | - | 5 | 10 | |
| Rise time | $t_r$ | | - | 15 | 30 | |
| Turn-off delay time | $t_{d(off)}$ | | - | 10 | 20 | |
| Fall time | $t_f$ | | - | 10 | 20 | |
| **Drain-Source Body Diode Characteristics** | | | | | | |
| Continuous source-drain diode current | $I_S$ | $T_C$ = 25 °C | - | - | 1.17 | A |
| Pulse diode forward current | $I_{SM}$ | | - | - | 15 | |
| Body diode voltage | $V_{SD}$ | $I_S$ = 2.7 A, $V_{GS}$ = 0 V | - | 0.85 | 1.2 | V |
| Body diode reverse recovery time | $t_{rr}$ | $I_F$ = 2.7 A, di/dt = 100 A/μs,<br>$T_J$ = 25 °C | - | 10 | 20 | ns |
| Body diode reverse recovery charge | $Q_{rr}$ | | - | 4 | 10 | nC |
| Reverse recovery fall time | $t_a$ | | - | 6 | - | ns |
| Reverse recovery rise time | $t_b$ | | - | 4 | - | |

**Notes**

a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%

b. Guaranteed by design, not subject to production testing

*Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*


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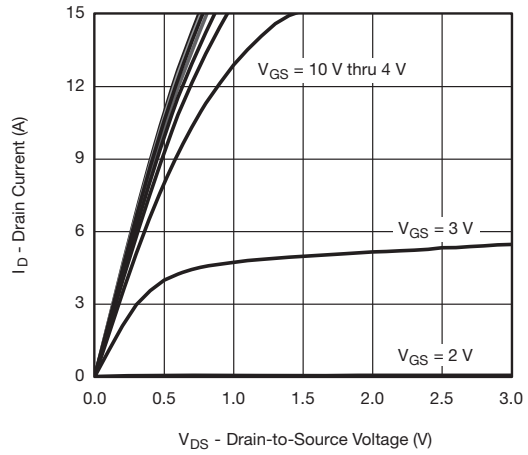
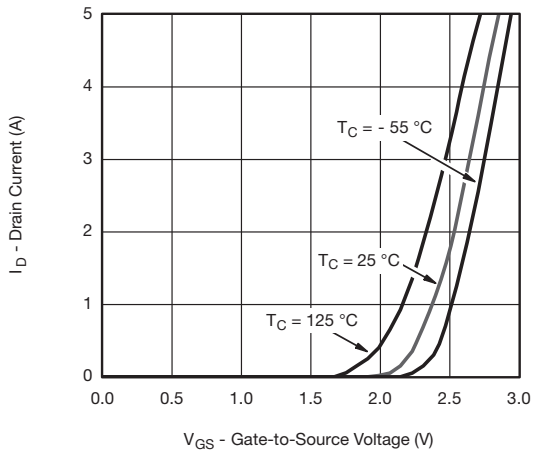
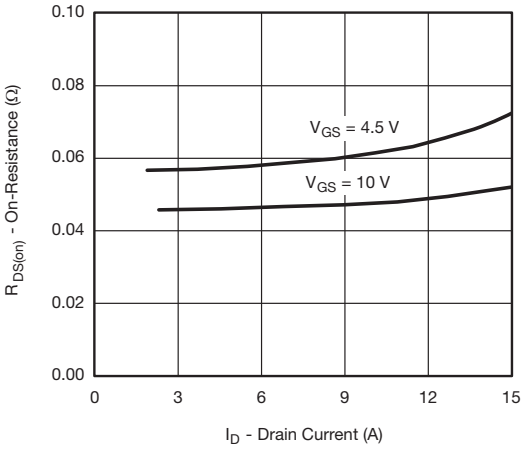
**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)



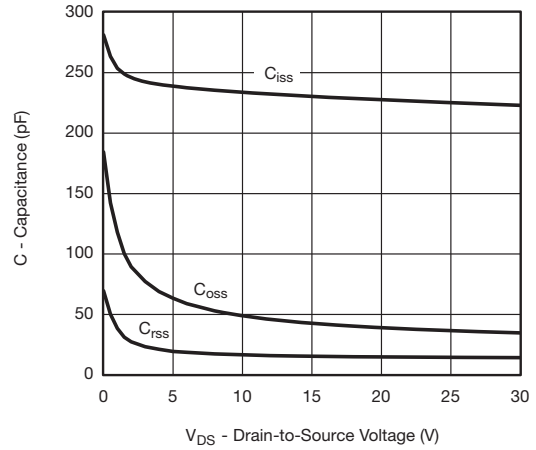

**Output Characteristics**



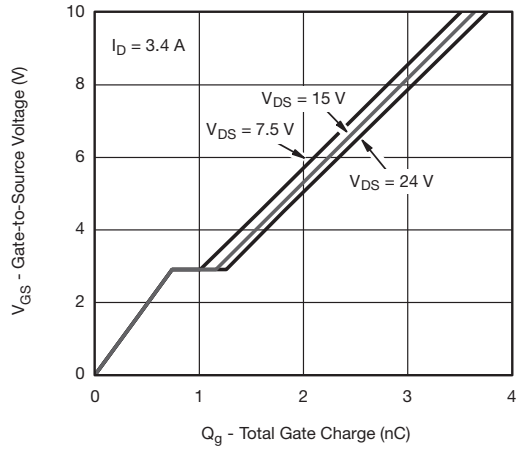

**Transfer Characteristics**



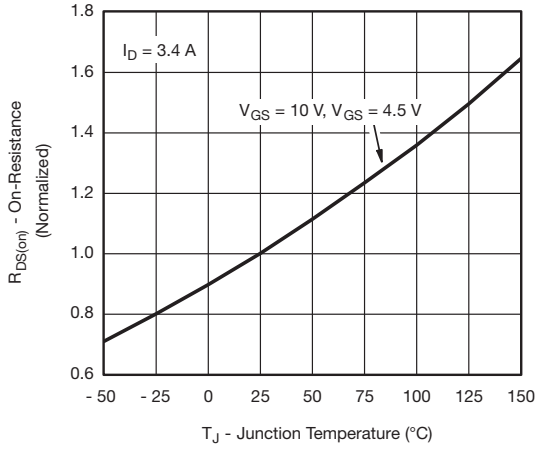

**On-Resistance vs. Drain Current and Gate Voltage**




**Capacitance**




**Gate Charge**




**On-Resistance vs. Junction Temperature**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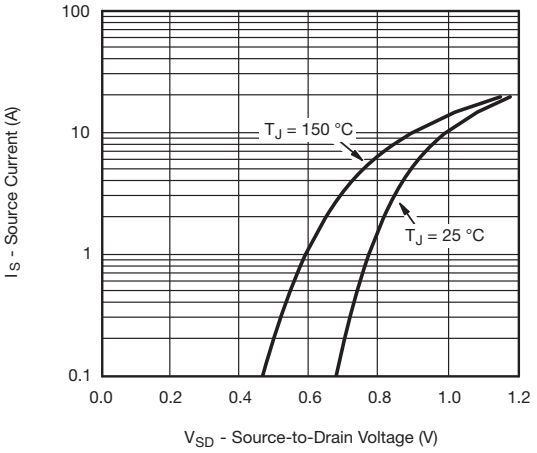
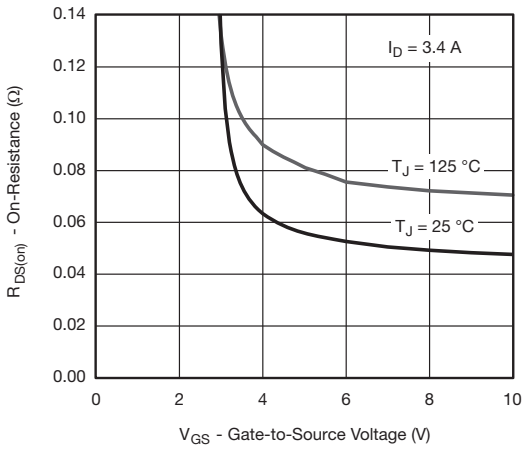
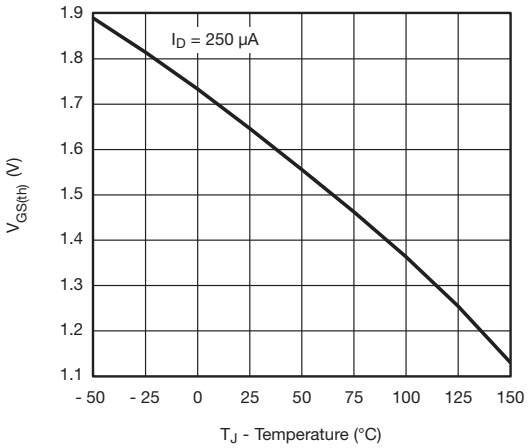


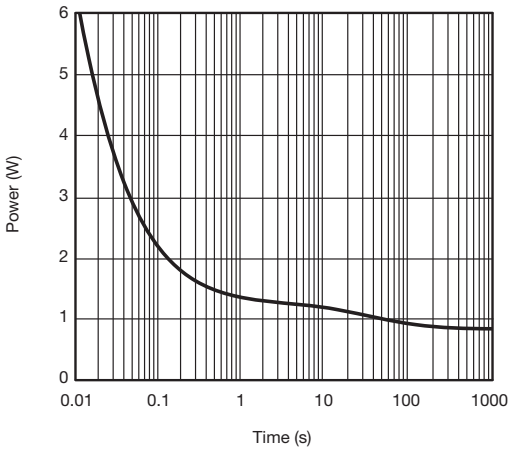

**Source-Drain Diode Forward Voltage**



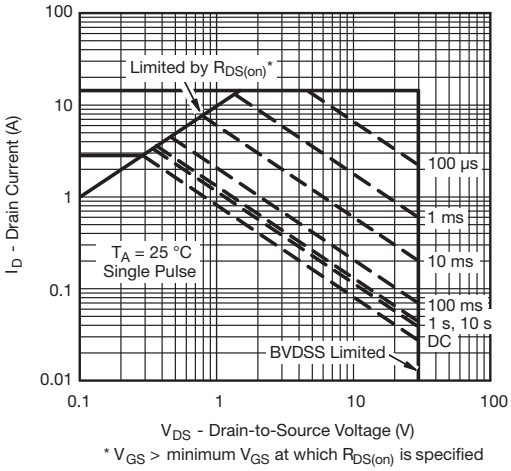

**On-Resistance vs. Gate-to-Source Voltage**




**Threshold Voltage**




**Single Pulse Power (Junction-to-Ambient)**




* $V_{GS}$ > minimum $V_{GS}$ at which $R_{DS(on)}$ is specified

**Safe Operating Area, Junction-to-Ambient**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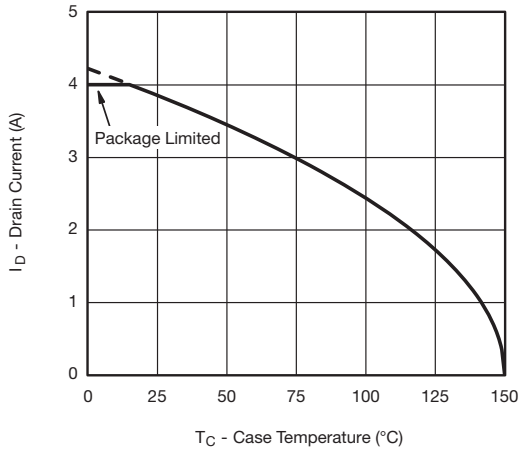
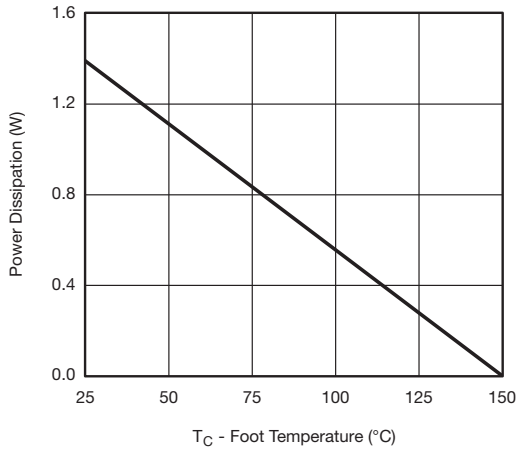



**Current Derating** [a]




**Power Derating**

**Note**

a. The power dissipation $P_D$ is based on $T_J$ max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit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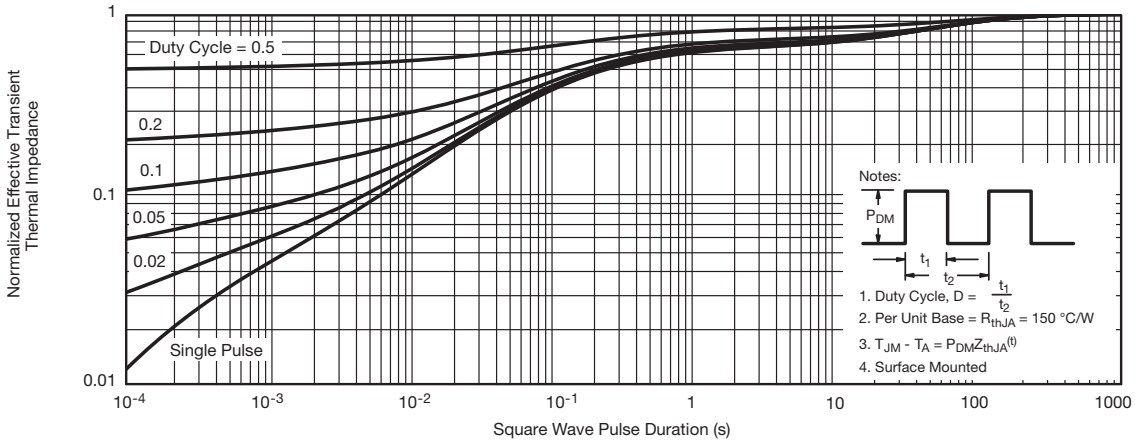
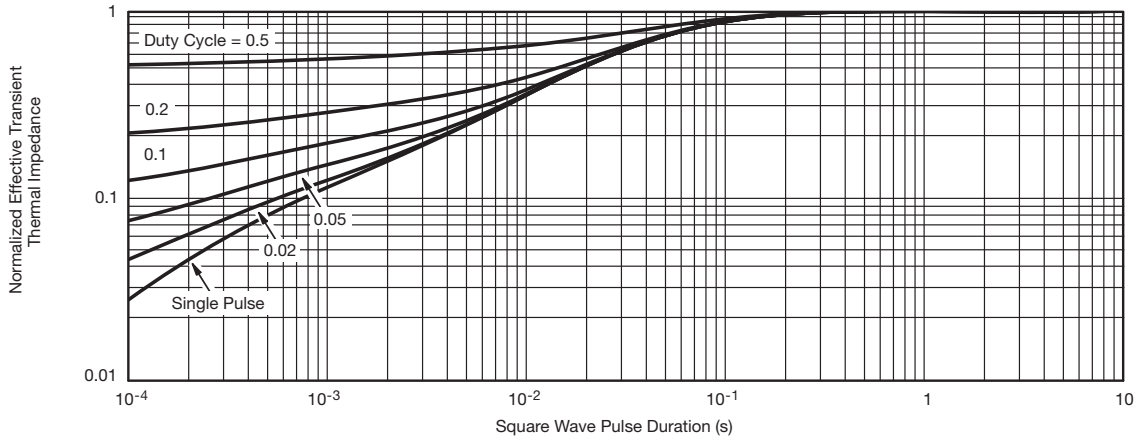



**Normalized Thermal Transient Impedance, Junction-to-Ambient**




**Normalized Thermal Transient Impedance, Junction-to-Foot**

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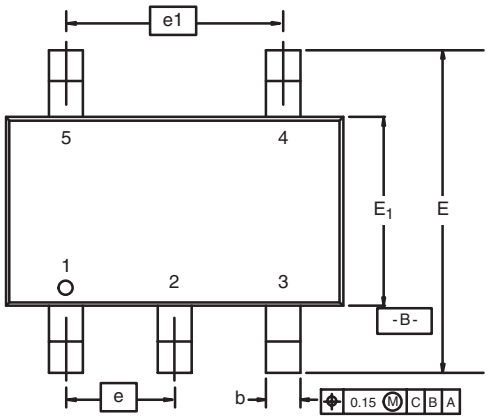
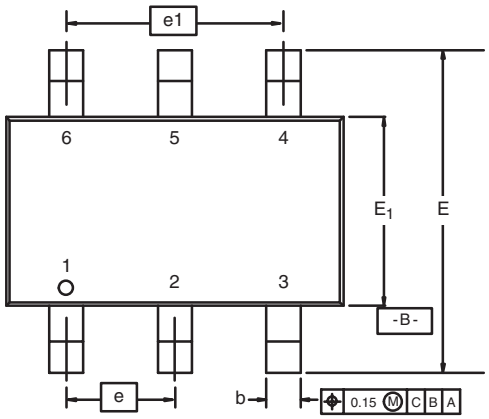
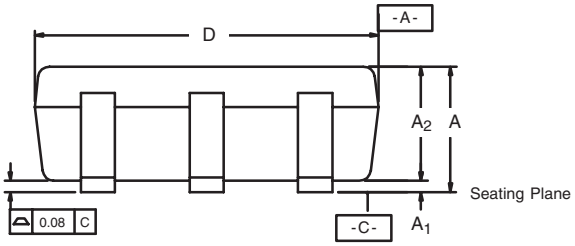
**TSOP: 5/6–LEAD**
**JEDEC Part Number: MO-193C**

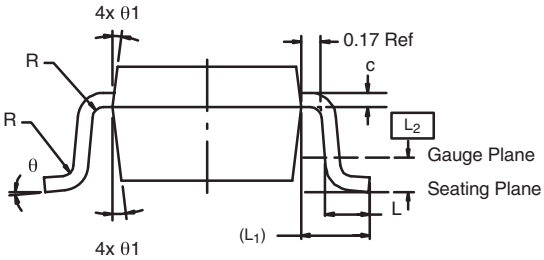



**5-LEAD TSOP**



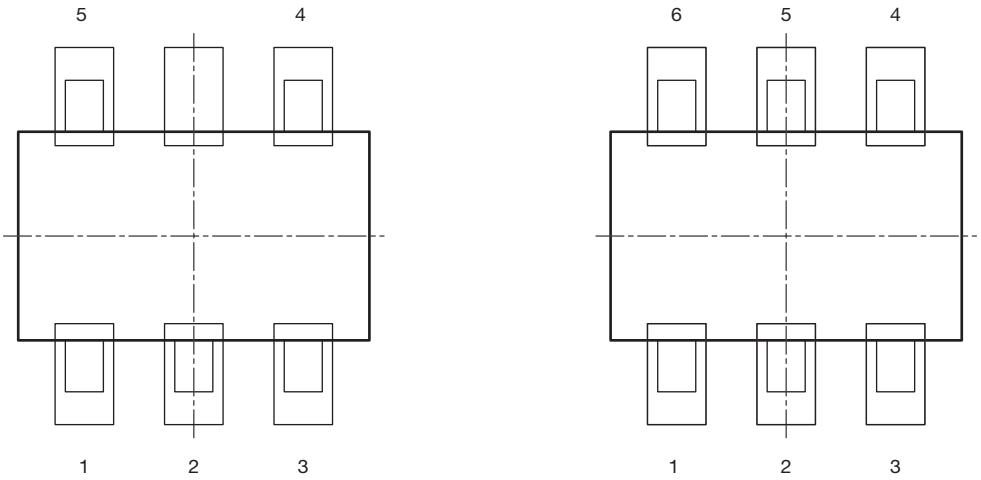

**6-LEAD TSOP**



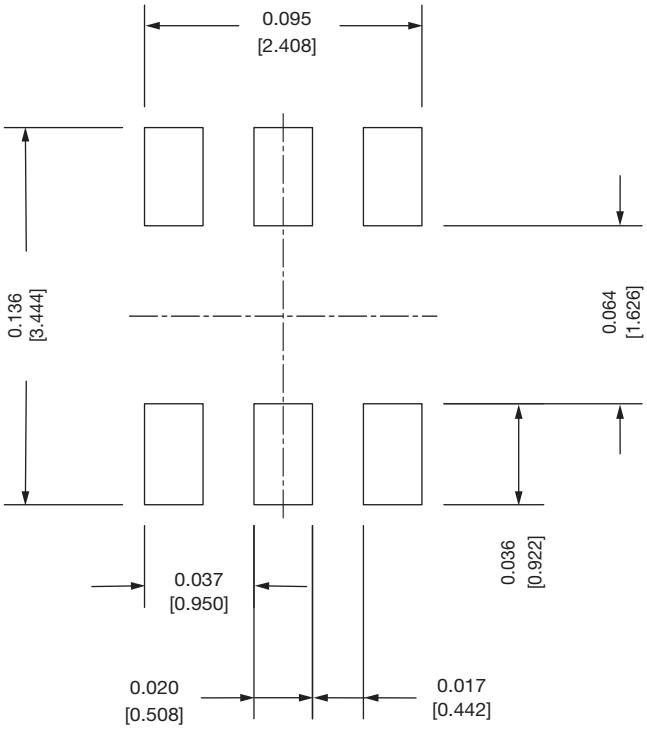

| Dim | MILLIMETERS | | | INCHES | | |
|---|---|---|---|---|---|---|
| | Min | Nom | Max | Min | Nom | Max |
| **A** | 0.91 | - | 1.10 | 0.036 | - | 0.043 |
| **$A_1$** | 0.01 | - | 0.10 | 0.0004 | - | 0.004 |
| **$A_2$** | 0.90 | - | 1.00 | 0.035 | 0.038 | 0.039 |
| **b** | 0.30 | 0.32 | 0.45 | 0.012 | 0.013 | 0.018 |
| **c** | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 |
| **D** | 2.95 | 3.05 | 3.10 | 0.116 | 0.120 | 0.122 |
| **E** | 2.70 | 2.85 | 2.98 | 0.106 | 0.112 | 0.117 |
| **$E_1$** | 1.55 | 1.65 | 1.70 | 0.061 | 0.065 | 0.067 |
| **e** | 0.95 BSC | | | 0.0374 BSC | | |
| **$e_1$** | 1.80 | 1.90 | 2.00 | 0.071 | 0.075 | 0.079 |
| **L** | 0.32 | - | 0.50 | 0.012 | - | 0.020 |
| **$L_1$** | 0.60 Ref | | | 0.024 Ref | | |
| **$L_2$** | 0.25 BSC | | | 0.010 BSC | | |
| **R** | 0.10 | - | - | 0.004 | - | - |
| θ | 0° | 4° | 8° | 0° | 4° | 8° |
| **$\theta_1$** | 7° Nom | | | 7° Nom | | |
| ECN: C-06593-Rev. I, 18-Dec-06<br>DWG: 5540 | | | | | | |

# Recommended Land Pattern For TSOP-5L / TSOP-6L




TSOP 5L

TSOP 6L




**Note**

- All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022
DWG: 3010



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